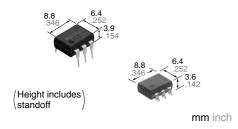


## Panasonic ideas for life

DIP 6-pin type with newgeneration MOS capable of 2A to 3A high-frequency load switching.

# PhotoMOS<sup>®</sup> HE 1 Form A High Capacity



#### **FEATURES**

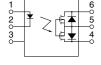
Greatly increased load current in a compact DIP package

Continuous load current: 3.5A (AQV251G)

2. Greatly improved specifications allow you to use this in place of mercury and mechanical relays. 3. Low on-resistance (typ.  $35m\Omega$ , AQV251G)

#### TYPICAL APPLICATIONS

- Measuring instrument market (Testers etc.)
- Industrial machinery and equipment
- Power supply controls
- Security/Disaster prevention market I/O sections of warning devices, security systems, etc.



**RoHS** compliant

#### **TYPES**

	Output rating*				Par				
			Package	Through hole terminal	Sı	rface-mount terminal		Packing quantity	
						Tape and reel packing style			
	Load voltage	Load current		Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	Tape and reel
AC/DC	New 30 V	3.5 A	DIP6-pin	AQV251G	AQV251GA	AQV251GAX	AQV251GAZ	1 tube contains: 50 pcs.	1,000 pcs.
dual use	60 V	2.5 A	DIP6-pin	AQV252G	AQV252GA	AQV252GAX	AQV252GAZ	1 batch contains: 500 pcs.	1,000 pcs.

<sup>\*</sup>Indicate the peak AC and DC values.

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

#### **RATING**

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

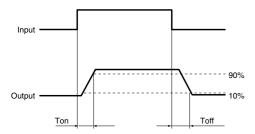
	Symbol	Type of connection	AQV251G(A)	AQV252G(A)	Remarks	
	LED forward current	lF		50	mA	
Input	LED reverse voltage	VR	1 \	5 V		
	Peak forward current	IFP	7 / [	1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation		] \ [	75 mW		
	Load voltage (peak AC)	VL	1 \	30 V	60 V	
		lι	Α	3.5 A	2.5 A	
Output	Continuous load current		В	4.0 A	3.5 A	A connection: Peak AC, DC B, C connection: DC
Output			С	6.0 A	5.0 A	B, & connection. Bo
	Peak load current	Ipeak		6.0 A		100ms (1 shot), V <sub>L</sub> = DC
	Power dissipation	Pout	] \	600	mW	
Total power dissipatio	Р⊤	] \ [	650	mW		
I/O isolation voltage		Viso	] \ [	1,500 V AC		
Tomporatura limita	Operating	Topr	] \ [	-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures
Temperature limits	Storage		1 \	-40°C to +100°C -40°F to +212°F		

#### HE 1 Form A High Capacity

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item				Type of connection	AQV251G(A)	AQV252G(A)	Condition
Input	LED anamata aurment	Typical	IFon	_	0.55 mA	0.5 mA	IL = 100mA
	LED operate current	Maximum			3 mA	3 mA	
	LED turn off current	Minimum	Foff	_	0.2 mA	0.2 mA	IL = 100mA
		Typical			0.45 mA	0.45 mA	
	LED dramaut valtage	Typical	VF	_	1.14 V (1.32 V at I <sub>F</sub> = 50 mA)		I <sub>F</sub> = 5 mA
	LED dropout voltage	Maximum			1.5 V		
Output	On resistance	Typical	Ron	А	0.035 Ω	0.08 Ω	IF = 5 mA IL = Max. Within 1 s on time
		Maximum			0.08 Ω	0.12 Ω	
		Typical	Ron	В	0.018 Ω	0.04 Ω	
		Maximum			0.04 Ω	0.06 Ω	
		Typical	Ron	С	0.01 Ω	0.02 Ω	
		Maximum			0.02 Ω	0.03 Ω	
	Off state leakage current	Maximum	Leak	_	1	ιA	$I_F = 0 \text{ mA}, V_L = \text{Max}.$
Transfer characteristics	Turn on time*	Typical	al Ton	_	1.1 ms		I <sub>F</sub> = 5 mA, I <sub>L</sub> = 100 mA V <sub>L</sub> = 10 V
	Turn on time	Maximum	Ion		5.0 ms		
	Turn off time*	Typical	Toff	_	0.1 ms	0.25 ms	I <sub>F</sub> = 5 mA, I <sub>L</sub> = 100 mA
	Turn on time	Maximum	loff		0.5 ms		V∟ = 10 V
	I/O conscitones	Typical	Ciso	_	0.8 pF		f = 1 MHz V <sub>B</sub> = 0 V
	I/O capacitance	Maximum	Ciso		1.5 pF		
	Initial I/O isolation resistance Minimum		Riso	_	1,000 ΜΩ		500 V DC

<sup>\*</sup>Turn on/Turn off time



#### RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit	
Input LED current	lF	5 to 10	mA	

- **■** For Dimensions.
- For Schematic and Wiring Diagrams.
- **■** For Cautions for Use.
- These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

For more information.

#### REFERENCE DATA

1.-(1) Load current vs. ambient temperature characteristics

Tested sample: AQV251G; Allowable ambient temperature:  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ 

4 C connection

B connection

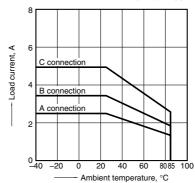
A connection

C connection

1.-(2) Load current vs. ambient temperature characteristics

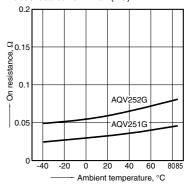
Tested sample: AQV252G;

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



2. On resistance vs. ambient temperature characteristics

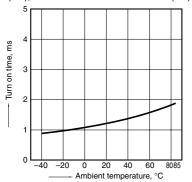
Measured portion: between terminals 4 and 6; LED current: 5 mA; Load voltage: Max. (DC) Continuous load current: Max.(DC)



#### HE 1 Form A High Capacity

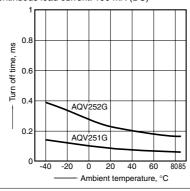
#### 3. Turn on time vs. ambient temperature characteristics

Tested sample: All; LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



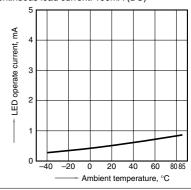
#### 4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



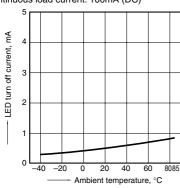
## 5. LED operate current vs. ambient temperature characteristics

Tested sample: All; Load voltage: 10 V (DC); Continuous load current: 100mA (DC)



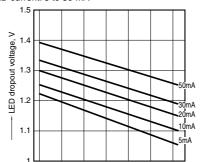
#### 6. LED turn off current vs. ambient temperature characteristics

Tested sample: All; Load voltage: 10 V (DC); Continuous load current: 100mA (DC)



## 7. LED dropout voltage vs. ambient temperature characteristics

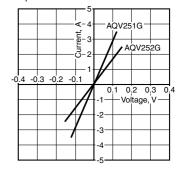
Tested sample: All; LED current: 5 to 50 mA



Ambient temperature, °C

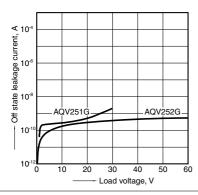
#### 8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



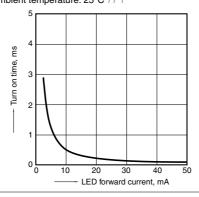
## 9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



## 10. Turn on time vs. LED forward current characteristics

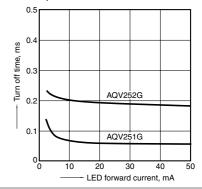
Measured portion: between terminals 4 and 6; Tested sample: All; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



## 11. Turn off time vs. LED forward current characteristics

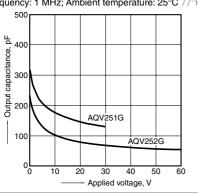
Measured portion: between terminals 4 and 6; Load voltage: 10 V (DC);

Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



## 12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



13. Max. switching frequency Tested sample: AQV251G; LED current: 5 mA;

Ambient temperature: 25°C 77°F

